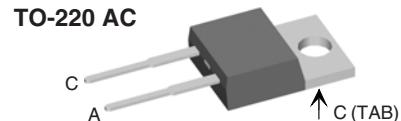


Power Schottky Rectifier

I_{FAV} = 10 A
V_{RRM} = 45 V
V_F = 0.56 V

V _{RSM} V	V _{RRM} V	Type
45	45	DSS 10-0045A



A = Anode, C = Cathode , TAB = Cathode

Symbol	Conditions	Maximum Ratings			Features
I _{FRMS}		35		A	
I _{FAV}	T _C = 160°C; rectangular, d = 0.5	10		A	
I _{FSM}	T _{VJ} = 45°C; t _p = 10 ms (50 Hz), sine	140		A	
E _{AS}	I _{AS} = 13 A; L = 180 µH; T _{VJ} = 25°C; non repetitive	24		mJ	
I _{AR}	V _A = 1.5 · V _{RRM} typ.; f=10 kHz; repetitive	1.3		A	
(dV/dt) _{cr}		1000		V/µs	
T _{VJ}		-55...+175		°C	
T _{VJM}		175		°C	
T _{stg}		-55...+150		°C	
P _{tot}	T _C = 25°C	90		W	
M _d	mounting torque	0.4...0.6		Nm	
Weight	typical	2		g	

Symbol	Conditions	Characteristic Values		Dimensions see Outlines.pdf
		typ.	max.	
I _R ①	V _R = V _{RRM} ; T _{VJ} = 25°C V _R = V _{RRM} ; T _{VJ} = 125°C	0.3 2.5	mA mA	
V _F	I _F = 10 A; T _{VJ} = 125°C I _F = 10 A; T _{VJ} = 25°C I _F = 20 A; T _{VJ} = 125°C	0.56 0.68 0.69	V V V	
R _{thJC} R _{thCH}		0.5	1.7 K/W K/W	

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %
Data according to IEC 60747 and per diode unless otherwise specified.

Recommended replacement:
DSA15I45PA

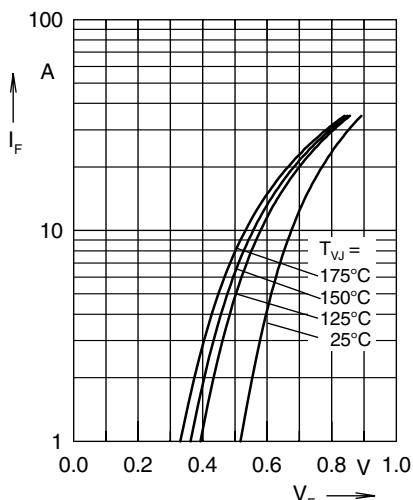


Fig. 1 Maximum forward voltage drop characteristics

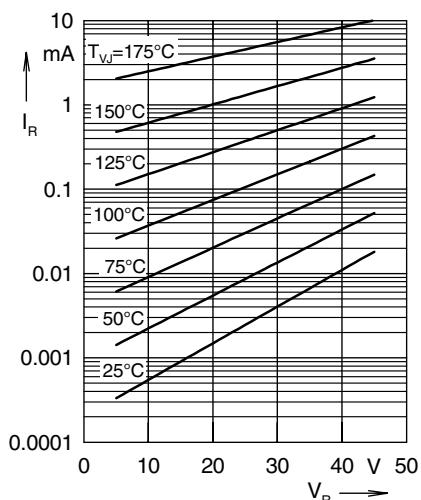


Fig. 2 Typ. value of reverse current I_R versus reverse voltage V_R

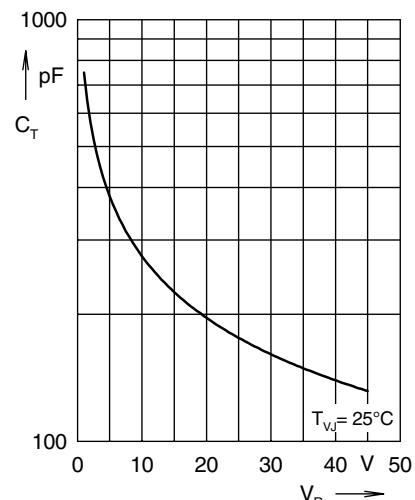


Fig. 3 Typ. junction capacitance C_T versus reverse voltage V_R

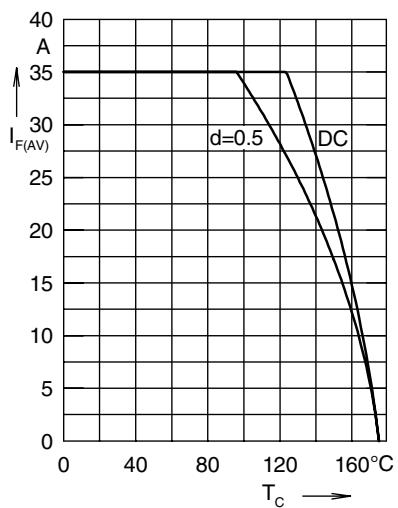


Fig. 4 Average forward current $I_{F(AV)}$ versus case temperature T_C

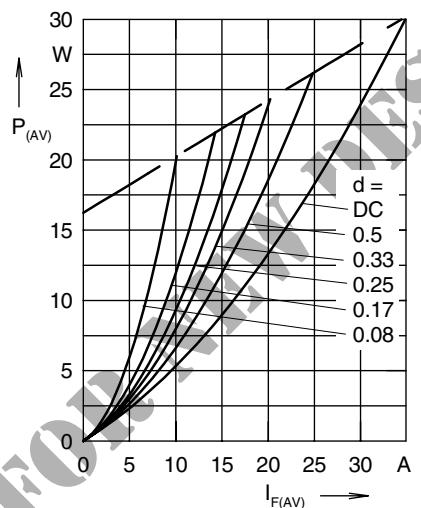


Fig. 5 Forward power loss characteristics

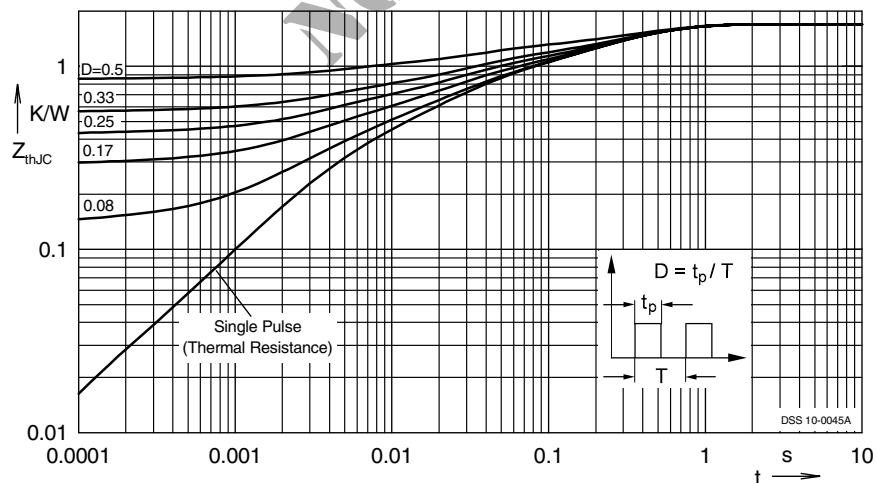


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode